## MCH6331

# Power MOSFET -30V, 98mΩ, -3.5A, Single P-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

### Features

- Low On-Resistance
- 4V drive
- Pb-Free, Halogen Free and RoHS compliance
- Ultra small package MCPH6 (2.0mm×2.1mm×0.85mmt)

### **Typical Applications**

Load Switch

## SPECIFICATIONS

## ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1, 2)

Parameter	Symbol	Value	Unit			
Drain to Source Voltage	VDSS	-30	V			
Gate to Source Voltage	VGSS	±20	V			
Drain Current (DC)	ID	-3.5	А			
Drain Current (Pulse) PW $\leq 10\mu$ s, duty cycle $\leq 1\%$	IDP	-14	А			
Power Dissipation When mounted on ceramic substrate (1200mm <sup>2</sup> × 0.8mm)	PD	1.5	w			
Junction Temperature	Tj	150	°C			
Storage Temperature	Tstg	–55 to +150	°C			

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

be assumed, damage may occur and reliability may be affected. 2 : This product is designed to "ESD immunity<200V\*", so please take care when handling.

\*Machine Model

## THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (1200mm <sup>2</sup> × 0.8mm)	R <sub>θJA</sub>	83.3	°C/W

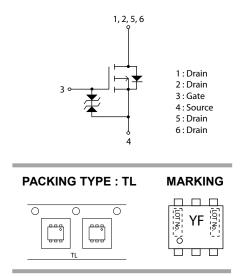


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VDSS	R <sub>DS</sub> (on) Max	ID Max
	98mΩ@ –10V	
-30V	171mΩ@ –4.5V	-3.5A
	199mΩ@ –4V	

#### ELECTRICAL CONNECTION P-Channel



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

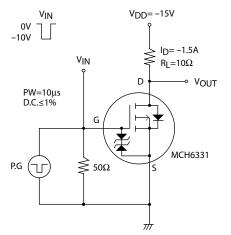
## MCH6331

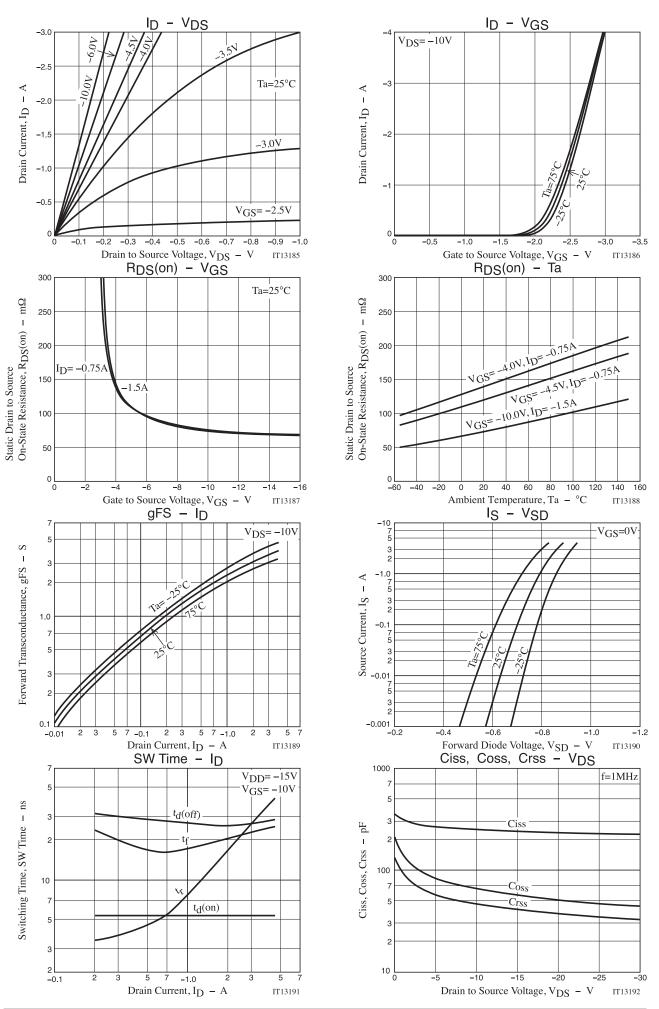
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Deremeter	Cumbol	Conditions	Value			Unit
Parameter	Symbol	Conditions	min	typ	max	Unii
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			-1	μA
Gate to Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transconductance	9FS	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1.5A	1.68	2.8		S
	R <sub>DS</sub> (on)1	ID=-1.5A, VGS=-10V		75	98	mΩ
Static Drain to Source On-State Resistance	R <sub>DS</sub> (on)2	ID=-0.75A, VGS=-4.5V		122	171	mΩ
Resistance	R <sub>DS</sub> (on)3	ID=-0.75A, VGS=-4V		142	199	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, f=1MHz		250		pF
Output Capacitance	Coss			65		pF
Reverse Transfer Capacitance	Crss			46		pF
Turn-ON Delay Time	t <sub>d</sub> (on)			5.4		ns
Rise Time	tr			12		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		26		ns
Fall Time	tf			19		ns
Total Gate Charge	Qg			5.0		nC
Gate to Source Charge	Qgs	V <sub>DS</sub> =-10V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.5A		1.0		nC
Gate to Drain "Miller" Charge	Qgd			1.2		nC
Forward Diode Voltage	VSD	IS=-3.5A, VGS=0V		-0.86	-1.5	V

Note 3 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

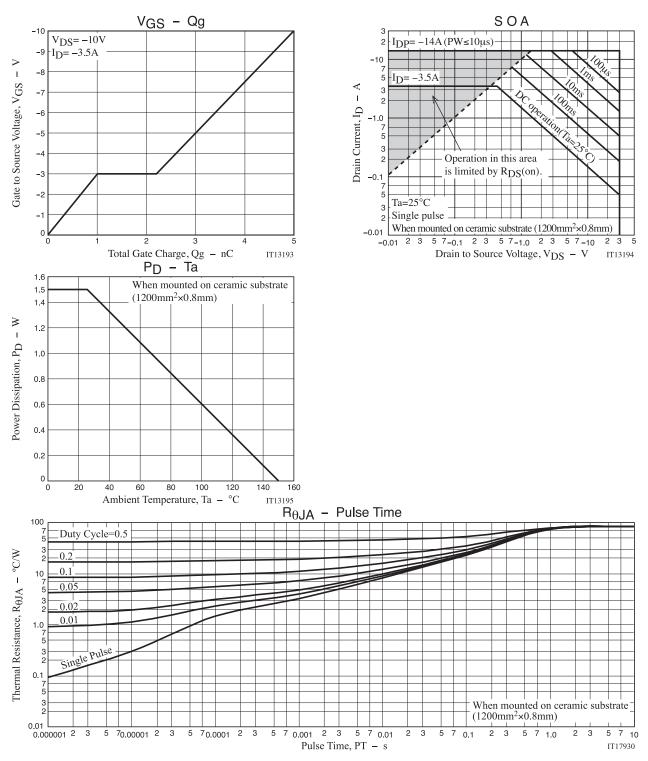
## Switching Time Test Circuit





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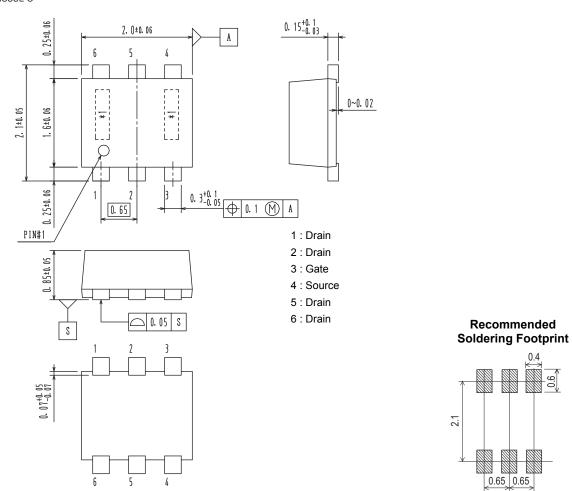
## MCH6331



## PACKAGE DIMENSIONS

unit : mm

SC-88FL / MCPH6 CASE 419AS ISSUE O



#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping (Qty / Packing)	
MCH6331-TL-H	YF	SC-88FL / MCPH6	3,000 / Tape & Reel	
MCH6331-TL-W	ĨF	(Pb-Free / Halogen Free)		

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub\_link/Collateral/BRD8011-D.PDF

# Note on usage : Since the MCH6331 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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